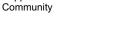


Sample &

Buy







TMP708

SBOS585B - DECEMBER 2011 - REVISED DECEMBER 2016

TMP708 Resistor-Programmable Temperature Switch in SOT Package

Technical

Documents

1 Features

- Threshold Accuracy:
 - ±0.5°C Typical
 - ±3°C Maximum (60°C to 100°C)
- Temperature Threshold Set By 1% External Resistor
- Low Quiescent Current: 40 μA, Typical
- Open-Drain, Active-Low Output Stage
- Pin-Selectable 10°C or 30°C Hysteresis
- Reset Operation Specified at V_{CC} = 0.8 V
- Supply Range: 2.7 V to 5.5 V
- Package: 5-Pin SOT-23

2 Applications

- Computers (Laptops and Desktops)
- Servers
- Industrial and Medical Equipment
- Storage Area Networks
- Automotive

3 Description

The TMP708 is a fully-integrated, resistorprogrammable temperature switch with a temperature threshold that is set by just one external resistor within the entire operating range. The TMP708 provides an open-drain, active-low output and has a 2.7-V to 5.5-V supply voltage range.

Support &

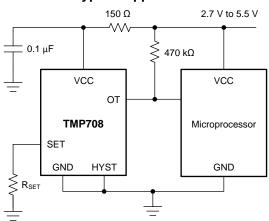
The temperature threshold accuracy is typically $\pm 0.5^{\circ}$ C, with a maximum of $\pm 3^{\circ}$ C (60°C to 100°C). The quiescent current consumption is typically 40 μ A. Hysteresis is pin-selectable to 10°C or 30°C.

The TMP708 is available in a 5-pin, SOT-23 package.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TMP708	SOT-23 (5)	2.90 mm x 1.60 mm

(1) For all available packages, see the package option addendum at the end of the datasheet.



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4 **Revision History**

•

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (February 2012) to Revision B

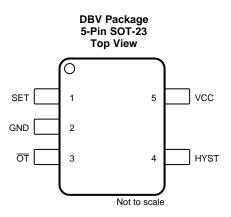
Cł	hanges from Original (December 2011) to Revision A	Page
•	Deleted Package and Ordering Information table; information now available in package option addendum located at the end of this data sheet	2
•	Added Device Information, ESD Ratings, and Recommended Operating Conditions tables, and Detailed Description, Application and Implementation, Power Supply Recommendations, Layout, Device and Documentation Support, and Mechanical, Packaging, and Orderable Information sections	

 	3	,-
Updated threshold accuracy feature bullet		1
Updated threshold accuracy text in second paragraph of Description section		1



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5 Pin Configuration and Functions



Pin Functions

PIN		ТҮРЕ	DESCRIPTION			
NAME	NO.	1175	DESCRIPTION			
GND	2	Analog power	Device ground			
HYST	4	Digital input	Hysteresis selection. For 10°C, HYST = VCC; for 30°C, HYST = GND.			
OT	3	Digital output	Open-drain, active low output			
SET	1	Analog input	Temperature set point. Connect an external 1% resistor between SET and GND.			
VCC	VCC 5 Analog power		Power-supply voltage (2.7 V to 5.5 V)			

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
	Supply, VCC	-0.3	6	
Voltage	Input, SET and HYST	-0.3	V _{CC} + 0.3	V
	Output, OT	-0.3	6	
Current .	Input		20	
Current	Output		20	mA
	Operating, T _A	-40	125	
Temperature	Junction, T _J		150	°C
	Storatge, T _{stg}	-65	150	

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD)		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±4000	
	Electrostatic discharge	ctrostatic discharge Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	V
	Machine model (MM	Machine model (MM)	±200	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
V _{CC}	Supply voltage	2.7	5.5	V
T _A	Operating temperature	0	125	°C

6.4 Thermal Information

		TMP708	
	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	UNIT
		5 PINS	
$R_{ hetaJA}$	Junction-to-ambient thermal resistance	217.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	86.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	44.6	°C/W
ΨJT	Junction-to-top characterization parameter	4.4	°C/W
Ψјв	Junction-to-board characterization parameter	43.8	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



6.5 Electrical Characteristics

at T_{A} = 0°C to 125°C and V_{CC} = 2.7 V to 5.5 V (unless otherwise noted)

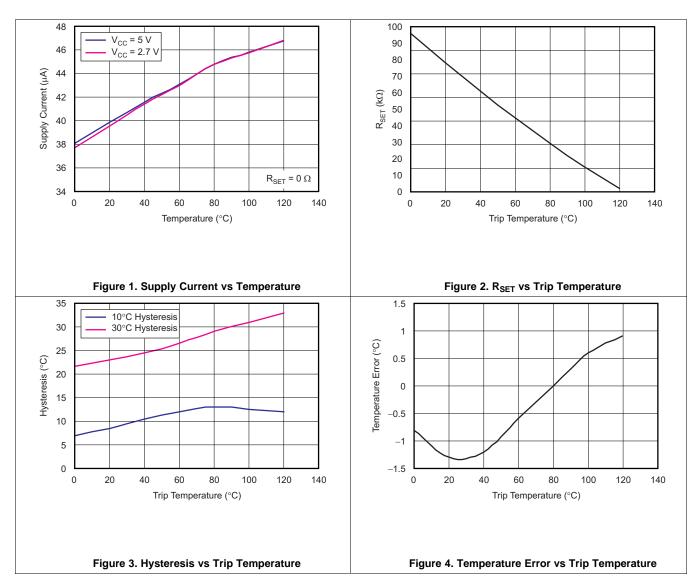
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER S	UPPLY					
	Cupply ourrent	$V_{CC} = 5 V$		40	55	μA
I _{CC}	Supply current	V _{CC} = 5 V V _{CC} = 2.7 V		40	55	μA
TEMPERA	TURE				·	
Τ _Ε	Temperature error	$T_{A} = 60^{\circ}C \text{ to } 100^{\circ}C$		±0.5	±3	°C
DIGITAL I	NPUT (HYST)				·	
V _{IH}	High-level input voltage		$0.7 \times V_{CC}$			V
V _{IL}	Low-level input voltage				$0.3 \times V_{CC}$	V
l _{lkg_in}	Input leakage current			1		μA
C _{IN}	Input capacitance			10		pF
ANALOG	NPUT (SET)					
V _{IN}	Input voltage range		0		V _{CC}	V
DIGITAL C	PEN-DRAIN OUTPUT (OT)				·	
I _(OT_SINK)	Output sink current	V _{OT} = 0.3 V	5	12		mA
I _{lkg(OT)}	Output leakage current	$V_{OT} = V_{CC}$		1		μA



TMP708 SBOS585B – DECEMBER 2011 – REVISED DECEMBER 2016

6.6 Typical Characteristics

at $T_A = 25^{\circ}C$ and $V_{CC} = 2.7$ V to 5.5 V (unless otherwise noted)





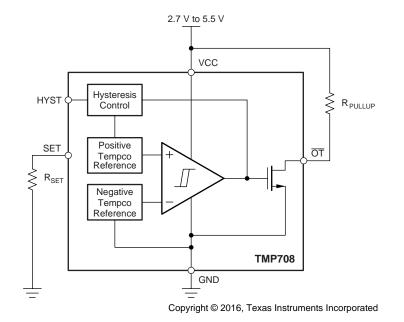
7 Detailed Description

7.1 Overview

The TMP708 is a fully-integrated, resistor-programmable temperature switch that incorporates two temperature dependent voltage references and one comparator. One voltage reference exhibits a positive temperature coefficient (tempco), and the other voltage reference exhibits a negative tempco. The temperature at which both voltage references are equal determines the temperature trip point.

The Functional Block Diagram shows the comparator, the NFET open-drain device connected to the \overline{OT} pin, the positive tempco reference using the external R_{SET} resistor, the negative tempco reference, and the hysteresis control. The voltage of the positive tempco reference is controlled by external resistor R_{SET}.

7.2 Functional Block Diagram





(1)

7.3 Feature Description

7.3.1 Temperature Switch

The TMP708 temperature threshold is programmable from 0°C to 125°C and is set by an external 1% resistor from the SET pin to the GND pin. The TMP708 has an open-drain, active-low output structure that easily interfaces with a microprocessor.

The TMP708 reaches the temperature trip point when the voltage from the positive tempco reference exceeds the voltage from the negative tempco reference. This difference causes the output of the comparator to switch from logic 0 to logic 1. The comparator output drives the gate of the NFET open-drain device, and pulls the voltage on the OT pin from logic 1 to logic 0 under these conditions; in other words, the output *trips*. Furthermore, the logic 1 output from the comparator causes the hysteresis control to increase the voltage of the PST pin; 30°C for logic 0 on the HYST pin). Increase the voltage of the positive tempco reference after the TMP708 trips to stop the TMP708 from untripping (voltage on the OT pin changing from logic 0 to logic 1) until the local temperature reduces by the amount set by the HYST pin. After the local temperature reduces, and the voltage from the positive tempco reference is less than the voltage from the negative tempco reference, the output of the comparator switches from logic 1 to logic 0. This condition causes the voltage on the OT pin to change from logic 0 to logic 1 to logic 1 to logic 0. This condition causes the voltage on the OT pin to change from logic 0 to logic 1 to logic 1 to logic 0. This condition causes the voltage on the OT pin to change from logic 0 to logic 1 (device untrips).

7.3.2 Hysteresis Input

The HYST pin is a digital input that allows the input hysteresis to be set at either $10^{\circ}C$ (when HYST = VCC) or $30^{\circ}C$ (when HYST = GND). The hysteresis function keeps the \overline{OT} pin from oscillating when the temperature is near the threshold. Thus, always connect the HYST pin to either VCC or GND. Other input voltages on this pin can cause abnormal supply currents or a device malfunction.

7.3.3 Set-Point Resistor (R_{SET})

Set the temperature threshold by connecting R_{SET} from the SET pin to GND. The value of R_{SET} is determined using either Figure 2 or Equation 1:

 R_{SET} (k Ω) = 0.0012T² - 0.9308T + 96.147

where

T = temperature threshold in degrees Celsius.

7.4 Device Functional Modes

The TMP708 device has a single functional mode. Normal operation for the TMP708 device occurs when the power-supply voltage applied across the VCC and GND pins is within the specified operating range of 2.7 V to 5.5 V.



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TMP708 device is simple to configure. The only external components that the device requires are a bypass capacitor and pullup resistor. Power-supply bypassing is strongly recommended. Use a 0.1- μ F capacitor placed as close as possible to the VCC supply pin. To minimize the internal power dissipation of the TMP708 family of devices, use a pullup resistor value greater than 10 k Ω from the \overline{OT} pin to the VCC pin. See the *Hysteresis Input* section for hysteresis configuration, and the *Set-Point Resistor* (R_{SET}) section for configuring the temperature threshold.

8.2 Typical Application

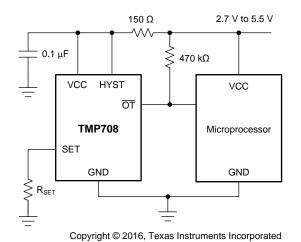


Figure 5. Overtemperature Protection for a 60°C Trip Point

8.2.1 Design Requirements

For this design example, a 2.7-V to 5.5-V power supply, 60°C trip point, and 10°C hysteresis are used.



Typical Application (continued)

8.2.2 Detailed Design Procedure

Connect the HYST pin to VCC for 10°C hysteresis. For a 60°C temperature threshold, see the *Set-Point Resistor* (R_{SET}) section to compute an ideal R_{SET} resistor value of 44.619 k Ω . Select the closest standard value resistor available; in this case, 44.2 k Ω . Use a 10-k Ω pullup resistor from the OT pin to the VCC pin. To minimize power, a larger-value pullup resistor can be used, but must not exceed 470 k Ω . Place a 0.1- μ F bypass capacitor close to the TMP708 device in order to reduce noise coupled from the power supply.

8.2.3 Application Curves

Figure 6 shows an example of the hysteresis feature. The HYST pin is connected to VCC, so the TMP708 device is configured for 10° C of hysteresis. The device is configured for a 60°C trip temperature by the R_{SET} resistor value; therefore, the OT output asserts low when the 60°C threshold is exceeded. The OT output remains asserted low until the sensor reaches 50°C.

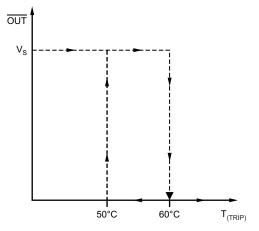


Figure 6. TMP708 Hysteresis Function



9 Power Supply Recommendations

The TMP708 low supply current and supply range allow this device to be powered from many sources. Any significant noise on the VCC pin can result in a trip-point error. Minimize this noise by low-pass filtering the device supply (V_{CC}) using a 150- Ω resistor and a 0.1- μ F capacitor.

10 Layout

10.1 Layout Guidelines

The TMP708 is extremely simple to lay out. Figure 7 shows the recommended board layout.

10.2 Layout Example

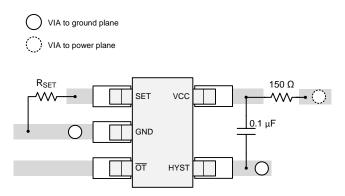


Figure 7. Recommended Layout

10.3 Thermal Considerations

The TMP708 quiescent current is typically 40 μ A. The device dissipates negligible power when the output drives a high-impedance load. Thus, the die temperature is the same as the package temperature. In order to maintain accurate temperature monitoring, provide a good thermal contact between the TMP708 package and the device being monitored. The rise in die temperature as a result of self-heating is given by Equation 2:

$$\Delta T_{J} = P_{DISS} \times \theta_{JA}$$

where

- P_{DISS} = power dissipated by the device.
 - θ_{JA} = package thermal resistance. Typical thermal resistance for SOT-23 package is 217.9°C/W. (2)

To limit the effects of self-heating, keep the output current at a minimum level.

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11 Device and Documentation Support

11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.3 Trademarks

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11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



2-Oct-2014

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TMP708AIDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SBI	Samples
TMP708AIDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SBI	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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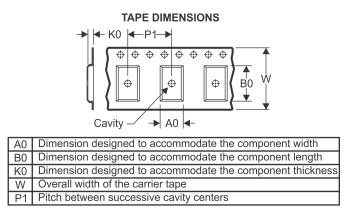
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



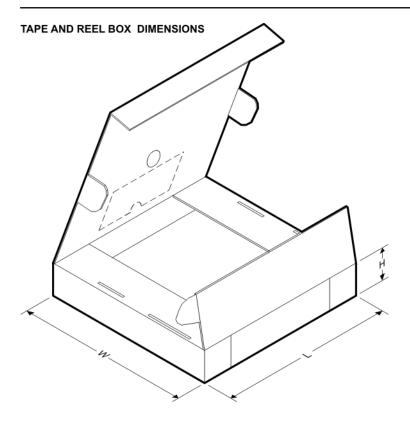
*All dimensions are ne	ominal											
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TMP708AIDBV	/R SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TMP708AIDB\	/T SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

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PACKAGE MATERIALS INFORMATION

2-Oct-2014



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TMP708AIDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TMP708AIDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- All linear dimensions are in millimeters. A.
 - This drawing is subject to change without notice. Β.
 - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side. C.
 - D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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